256K x 4 Bit Fast Static Random Access Memory

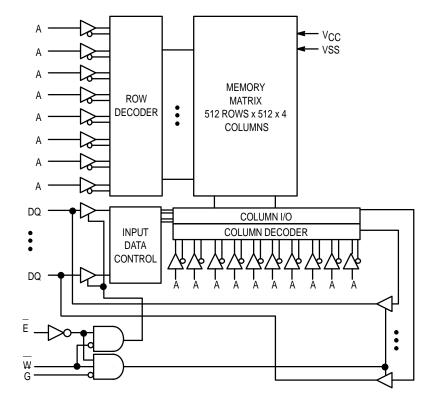
The MCM6729C is a 1,048,576 bit static random access memory organized as 262,144 words of 4 bits. Static design eliminates the need for external clocks or timing strobes. __

Output enable (G) is a special control feature that provides increased system flexibility and eliminates bus contention problems.

This device meets JEDEC standards for functionality and revolutionary pinout, and is available in a 400 mil plastic small—outline J—leaded package.

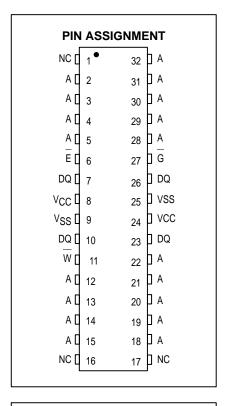
- Single 5 V \pm 10% Power Supply
- Fully Static No Clock or Timing Strobes Necessary
- · All Inputs and Outputs Are TTL Compatible
- Three State Outputs
- Fast Access Times: 6, 7 ns
- · Center Power and I/O Pins for Reduced Noise

BLOCK DIAGRAM



MCM6729C





REV 3 10/9/96



TRUTH TABLE (X = Don't Care)

E	G	W	Mode	V _{CC} Current	Output	Cycle
Н	Х	Х	Not Selected I _{SB1} , I _{SB2}		High–Z	
L	Н	Н	Output Disabled	out Disabled ICCA		_
L	L	Н	Read	ICCA	D _{out}	Read Cycle
L	Х	L	Write	ICCA	High-Z	Write Cycle

ABSOLUTE MAXIMUM RATINGS (See Note)

Rating	Symbol	Value	Unit
Power Supply Voltage	Vcc	- 0.5 to + 7.0	V
Voltage Relative to VSS for Any Pin Except $^{ m VCC}$	V _{in} , V _{out}	- 0.5 to V _{CC} + 0.5	V
Output Current	l _{out}	±30	mA
Power Dissipation	PD	1.5	W
Temperature Under Bias	T _{bias}	– 10 to + 85	°C
Operating Temperature	TA	0 to + 70	°C
Storage Temperature — Plastic	T _{stg}	- 55 to + 125	°C

NOTE: Permanent device damage may occur if ABSOLUTE MAXIMUM RATINGS are exceeded. Functional operation should be restricted to RECOMMENDED OPER-ATING CONDITIONS. Exposure to higher than recommended voltages for extended periods of time could affect device reliability.

This device contains circuitry to protect the inputs against damage due to high static voltages or electric fields; however, it is advised that normal precautions be taken to avoid application of any voltage higher than maximum rated voltages to these high-impedance circuits.

This BiCMOS memory circuit has been designed to meet the dc and ac specifications shown in the tables, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow of at least 500 linear feet per minute is maintained.

DC OPERATING CONDITIONS AND CHARACTERISTICS

(V_{CC} = 5.0 V \pm 10%, T_A = 0 to 70°C, Unless Otherwise Noted)

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Min	Тур	Max	Unit
Supply Voltage (Operating Voltage Range)	Vcc	4.5	5.0	5.5	V
Input High Voltage	VIH	2.2	_	V _{CC} + 0.3**	V
Input Low Voltage	V _{IL}	- 0.5*	1	0.8	V

^{*} V_{IL} (min) = -0.5 V dc; V_{IL} (min) = -2.0 V ac (pulse width ≤ 2.0 ns) for $I \le 20.0$ mA.

DC CHARACTERISTICS

Parameter	Symbol	Min	Max	Unit
Input Leakage Current (All Inputs, V _{in} = 0 to V _{CC})	l _{lkg(I)}	-	± 1.0	μΑ
Output Leakage Current (E = V _{IH} , V _{Out} = 0 to V _{CC})	l _{lkg(O)}	_	± 1.0	μΑ
Output Low Voltage (I _{OL} = + 8.0 mA)	VOL	_	0.4	V
Output High Voltage (I _{OH} = - 4.0 mA)	Voн	2.4	_	V

POWER SUPPLY CURRENTS

Parameter	Symbol	MCM6729C-6	MCM6729C-7	Unit	Notes
AC Active Supply Current (I _{out} = 0 mA) (V _{CC} = max, f = f _{max})	ICCA	250	220	mA	1, 2, 3
Active Quiescent Current (E = V _{IL} , V _{CC} = max, f = 0 MHz)	I _{CC2}	100	100	mA	
AC Standby Current (E = V _{IH} , V _{CC} = max, f = f _{max})	I _{SB1}	100	100	mA	1, 2, 3
CMOS Standby Current (V_{CC} = max, f = 0 MHz, E \geq V_{CC} - 0.2 V, $V_{in} \leq$ V_{SS} + 0.2 V, or \geq V_{CC} - 0.2 V)	I _{SB2}	60	60	mA	

NOTES:

- 1. Reference AC Operating Conditions and Characterisitics for input and timing $(V_{IH}/V_{IL}, t_f/t_f, pulse level 0 to 3 V, V_{IH} = 3 V)$.
- 2. All addresses transition simultaneously low (LSB) and then high (MSB).
- 3. Data States are all zero.

^{**} V_{IH} (max) = V_{CC} + 0.3 V dc; V_{IH} (max) = V_{CC} + 2 V ac (pulse width \leq 2.0 ns) for $I \leq$ 20.0 mA.

CAPACITANCE (f = 1.0 MHz, dV = 3.0 V, T_A = 25°C, Periodically Sampled Rather Than 100% Tested)

Parameter	Symbol	Тур	Max	Unit
Address Input Capacitance	C _{in}	_	6	pF
Control Pin Input Capacitance	C _{in}	_	6	pF
Input/Output Capacitance	C _{I/O}	_	8	pF

AC OPERATING CONDITIONS AND CHARACTERISTICS

(V_{CC} = 5.0 V \pm 10%, T_A = 0 to +70°C, Unless Otherwise Noted)

Input Timing Measurement Reference Level 1.5 V	Output Timing Measurement Reference Level 1.5 V
Input Pulse Levels 0 to 3.0 V	Output Load See Figure 1a
Input Rise/Fall Time	

READ CYCLE TIMING (See Notes 1 and 2)

		MCM6729C-6		MCM6729C-6		мсм6	729C-7		
Parameter	Symbol	Min	Max	Min	Max	Unit	Notes		
Read Cycle Time	tAVAV	6	_	7	_	ns	3		
Address Access Time	†AVQV	_	6	_	7	ns			
Enable Access Time	^t ELQV	_	6	_	7	ns			
Output Enable Access Time	^t GLQV		4	_	4	ns			
Output Hold from Address Change	t _A XQX	2	_	2	_	ns			
Enable Low to Output Active	^t ELQX	3	_	3	_	ns	4,5,6		
Output Enable Low to Output Active	^t GLQX	0	_	0	_	ns	4,5,6		
Enable High to Output High–Z	t _{EHQZ}	-	3	_	3.5	ns	4,5,6		
Output Enable High to Output High–Z	^t GHQZ	-	3	_	3.5	ns	4,5,6		

NOTES:

- 1. W is high for read cycle.
- 2. For common I/O applications, minimization or elimination of bus contention conditions is necessary during read and write cycles.
- 3. All read cycle timings are referenced from the last valid address to the first transitioning address.
- At any given voltage and temperature, t_{EHQZ} (max) < t_{ELQX} (min), and t_{GHQZ} (max) < t_{GLQX} (min), both for a given device and from device to device.
- 5. Transition is measured 200 mV from steady-state voltage with load of Figure 1b.
- 6. This parameter is sampled and not 100% tested.
- 7. Device is continuously selected (E = $V_{\parallel}L$, $G = V_{\parallel}L$).
- 8. Addresses valid prior to or coincident with E going low.

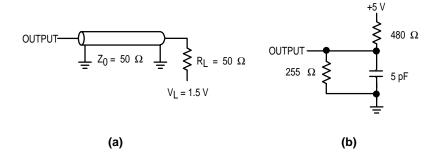


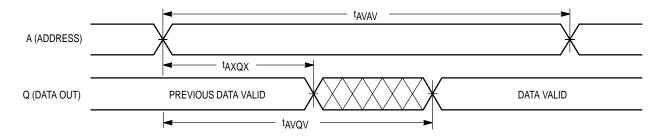
Figure 1. AC Test Loads

TIMING LIMITS

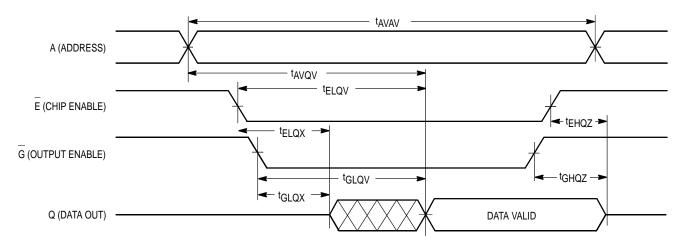
The table of timing values shows either a minimum or a maximum limit for each parameter. Input requirements are specified from the external system point of view. Thus, address setup time is shown as a minimum since the system must supply at least that much time On the other hand, responses from the memory are specified from the device point of view. Thus, the access time is shown as a maximum since the device never provides data later than that time.

MOTOROLA FAST SRAM MCM6729C

READ CYCLE 1 (See Note 7)



READ CYCLE 2 (See Note 8)



MCM6729C MOTOROLA FAST SRAM

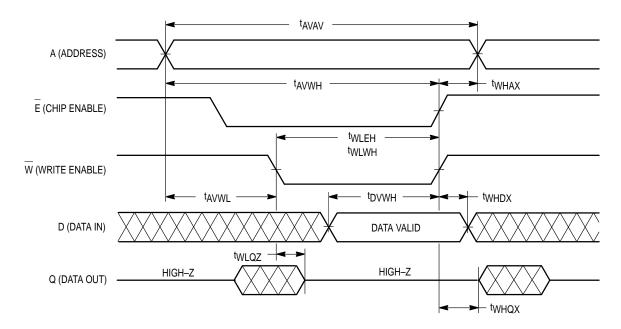
WRITE CYCLE 1 (W Controlled, See Notes 1 and 2)

		MCM6729C-6		МСМ67	729C-7		
Parameter	Symbol	Min	Max	Min	Max	Unit	Notes
Write Cycle Time	t _{AVAV}	6	_	7	_	ns	3
Address Setup Time	†AVWL	0	_	0	_	ns	
Address Valid to End of Write	^t AVWH	6	_	7	_	ns	
Address Valid to End of Write, G High	^t AVWH	6	_	7	_	ns	
Write Pulse Width	tWLWH tWLEH	6	_	7	_	ns	
Write Pulse Width, G High	tWLWH tWLEH	6	_	7	_	ns	
Data Valid to End of Write	^t DVWH	3	_	3.5	_	ns	
Data Hold Time	tWHDX	0	_	0	_	ns	
Write Low to Data High–Z	tWLQZ	_	3.5	_	3.5	ns	4,5,6
Write High to Output Active	tWHQX	3		3		ns	4,5,6
Write Recovery Time	tWHAX	1	_	1	_	ns	

NOTES:

- 1. A write occurs during the overlap of E low and $\overline{\mathrm{W}}$ low.
- 2. For common I/O applications, minimization or elimination of bus contention conditions is necessary during read and write cycles.
- 3. All write cycle timings are referenced from the last valid address to the first transitioning address.
- 4. Transition is measured 200 mV from steady-state voltage with load of Figure 1b.
- 5. This parameter is sampled and not 100% tested.
- 6. At any given voltage and temperature, t_{WLQZ} max < t_{WHQX} min both for a given device and from device to device.

WRITE CYCLE 1



MOTOROLA FAST SRAM MCM6729C

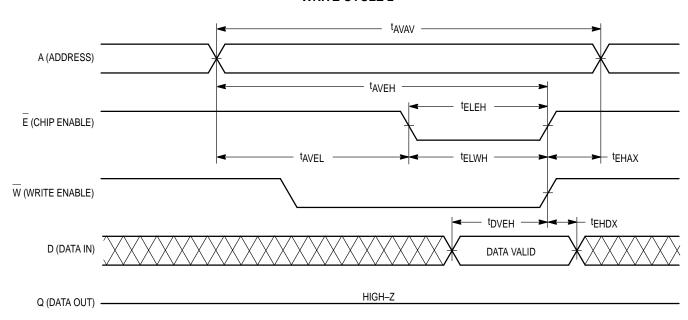
WRITE CYCLE 2 (E Controlled, See Notes 1 and 2)

		MCM6729C-6		9C-6 MCM67			
Parameter	Symbol	Min	Max	Min	Max	Unit	Notes
Write Cycle Time	t _{AVAV}	6	_	7	_	ns	3
Address Setup Time	^t AVEL	0	_	0	_	ns	
Address Valid to End of Write	^t AVEH	6	_	7	_	ns	
Enable to End of Write	^t ELEH ^t ELWH	5	_	6	_	ns	4,5
Data Valid to End of Write	^t DVEH	3	_	3.5	_	ns	
Data Hold Time	^t EHDX	0	_	0	_	ns	
Write Recovery Time	t _{EHAX}	0	_	0	_	ns	

NOTES:

- 1. A write occurs during the overlap of E low and W low.
- 2. For common I/O applications, minimization or elimination of bus contention conditions is necessary during read and write cycles.
- 3. All write cycle timings are referenced from the last valid address to the first transitioning address.
- 4. If $\underline{\underline{E}}$ goes low coincident with or after W $\underline{\underline{o}}$ es low, the output will remain in a high impedance condition.
- 5. If E goes high coincident with or before W goes high, the output will remain in a high impedance condition.

WRITE CYCLE 2



ORDERING INFORMATION (Order by Full Part Number)



Full Part Numbers — MCM6729CWJ6 MCM6729CWJ7 MCM6729CWJ7R MCM6729CWJ7R

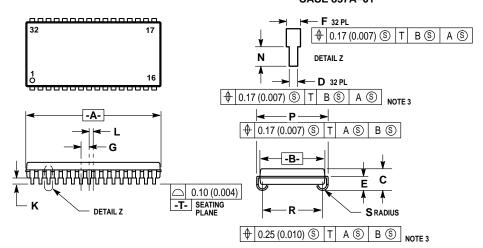
MCM6729C MOTOROLA FAST SRAM

Motorola Memory Prefix

Part Number -

PACKAGE DIMENSIONS

32-LEAD 400 MIL SOJ CASE 857A-01



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI
- CONTROLLING DIMENSION: INCH.
- TO BE DETERMINED AT PLANE -T.
 DIMENSION A & B DO NOT INCLUDE MOLD
 PROTRUSION. MOLD PROTRUSION SHALL NOT
- EXCEED 0.15 (0.006) PER SIDE.
 DIMENSION A & B INCLUDE MOLD MISMATCH AND ARE DETERMINED AT THE PARTING LINE.

MILLIMETERS INCHES						
DIM	MIN	MAX	MIN	MAX		
Α	20.83	21.08	0.820	0.830		
В	10.03	10.29	0.395	0.405		
С	3.26	3.75	0.128	0.148		
D	0.41	0.50	0.016	0.020		
Е	2.24	2.48	0.088	0.098		
F	0.67	0.81	0.026	0.032		
G	1.27	BSC	0.050 BSC			
K	0.89	1.14	0.035	0.045		
L	0.64	BSC	0.02	BSC		
N	0.89	1.14	0.035	0.045		
Р	11.05	11.30	0.435	0.445		
R	9.27	9.52	0.365	0.375		
S	0.77	1.01	0.030	0.040		

Motorola reserves the right to make changes without further notice to any products herein. Motorola makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Motorola assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters which may be provided in Motorola data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. Motorola does not convey any license under its patent rights nor the rights of others. Motorola products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Motorola product could create a situation where personal injury or death may occur. Should Buyer purchase or use Motorola products for any such unintended or unauthorized application, Buyer shall indemnify and hold Motorola and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Motorola was negligent regarding the design or manufacture of the part. Motorola and (A) are registered trademarks of Motorola, Inc. Motorola, Inc. is an Equal Opportunity/Affirmative Action Employer.

How to reach us:

USA/EUROPE/Locations Not Listed: Motorola Literature Distribution; P.O. Box 5405, Denver, Colorado 80217. 303-675-2140 or 1-800-441-2447

Mfax™: RMFAX0@email.sps.mot.com - TOUCHTONE 602-244-6609 - US & Canada ONLY 1-800-774-1848

JAPAN: Nippon Motorola Ltd.: SPD, Strategic Planning Office, 4-32-1, Nishi-Gotanda, Shinagawa-ku, Tokyo 141, Japan. 81-3-5487-8488

ASIA/PACIFIC: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park, 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852-26629298

Mfax is a trademark of Motorola, Inc.

INTERNET: http://motorola.com/sps



MCM6729C/D